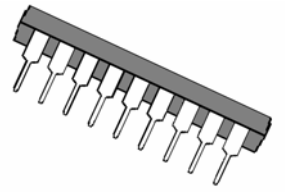
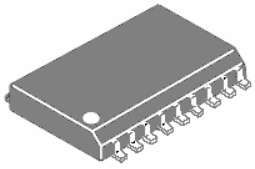
Octal High Voltage,High Current Darlington Transistor Arrays



ULN2803AD DIP-18



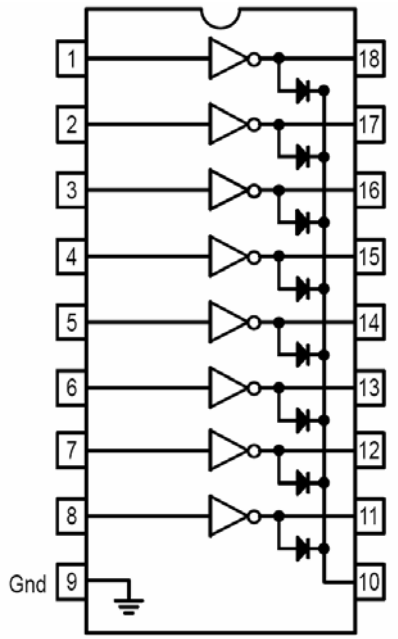
ULN2803AS SOP-18

DESCRIPTIONS:

The eight NPN Darlington connected transistors in this family of arrays are ideally suited for interfacing between low logic level digital circuitry (such as TTL, CMOS or PMOS/NMOS) and the higher current/voltage requirements of lamps, relays, printer hammers or other similar loads for a broad range of computer, industrial, and consumer applications. All devices feature open–collector outputs and free wheeling clamp diodes for transient suppression

The ULN2803 is designed to be compatible with standard TTL families while the ULN2804 is optimized for 6 to 15 volt high level CMOS or PMOS.

PIN CONNECTION



ABSOLUTE MAXIMUM RATINGS (T_A = 25°C and rating apply to any one device in the package, unless otherwise noted.)

Characteristic	Symbol	Value	Unit
Output voltage	V_O	50	V
Input voltage	V_I	30	V
Collector current- continuous	I_C	500	mA
Base current- continuous	I_B	25	mA
Operating temperature	Topr	0～70	°C
Storage temperature	Tstg	-55～+150	°C
Junction temperature	T_J	125	°C

* $R_{\theta JA}$=55°C/W

Do not exceed maximum current limit per driver.

ELECTRICAL CHARACTERISTICS

(unless otherwise specified: T_A=25°C)

Characteristics	Symbol	Test conditions	Min	Typ	Max	Unit
Output leakage current (Fig.1)	I_{CEX}	Vo=50V, T_A=70°C			100	µA
		Vo=50V, T_A=25°C			50	
Collector-Emitter saturation voltage (Fig.2)	$V_{CE(sat)}$	Ic=350mA,I_B=500µA		1.1	1.6	V
		Ic=200mA,I_B=350µA		0.95	1.3	
		Ic=100mA,I_B=250µA		0.85	1.1	
Input current - on condition (Fig.4)	$I_{I(on)}$	V_I=3.85V		1.1	1.35	mA
Input voltage - on condition (Fig.5)	$V_{I(on)}$	V_{CE}=2.0V,I_C=200mA		1.70	2.4	V
		V_{CE}=2.0V,I_C=250mA		1.75	2.7	
		V_{CE}=2.0V,I_C=300mA		1.80	3.0	
Input current - off condition (Fig.3)	$I_{I(off)}$	I_C=500µA, T_A=70°C	50	100		µA
Input capacitance	C_I			15	25	pF
Turn-on delay time (50% E_I to 50% E_O)	ton			0.25	1.0	µs
Turn-off delay time (50% E_I to 50% E_O)	toff			0.25	1.0	µs
Clamp diode leakage current (V_R=50V) (Fig.6)	I_R	T_A=25°C			50	µA
		T_A=70°C			100	
Clamp diode forward Voltage (Fig.7)	V_F	I_F=350mA		1.5	2.0	V

TEST CIRCUIT

Figure 1.

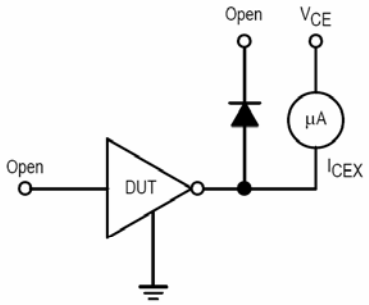


Figure 2.

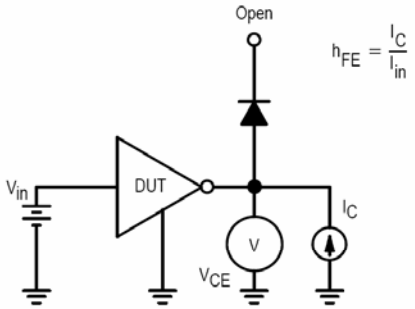


Figure 3.

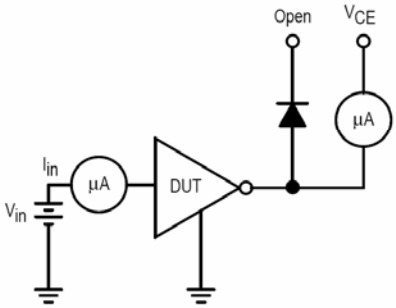


Figure 4.

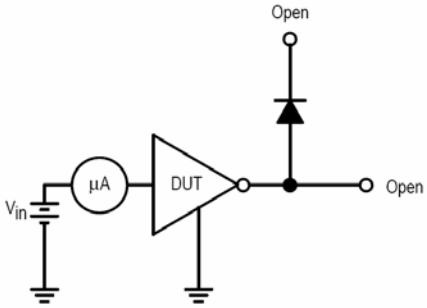


Figure 5.

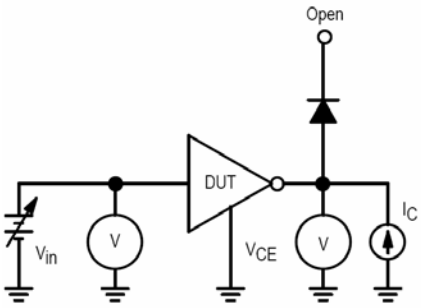


Figure 6.

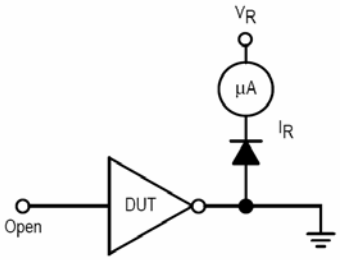
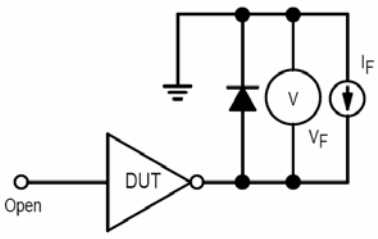
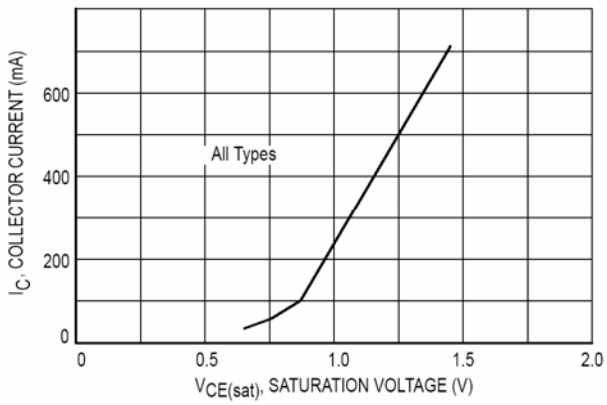


Figure 7.

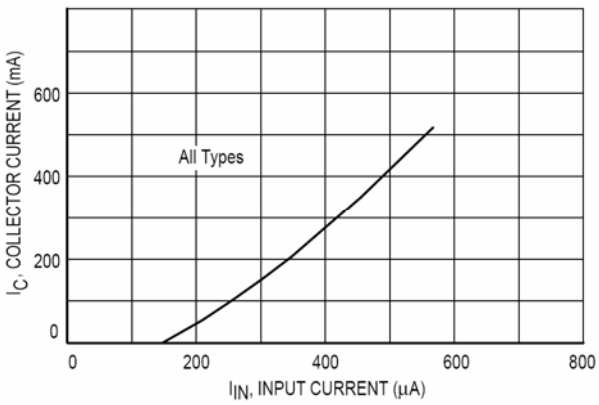


TYPICAL CURVE

Output Current versus Saturation Voltage

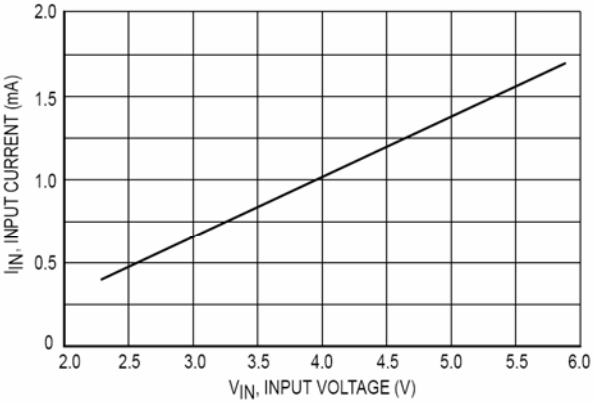


Output Current versus Input Current



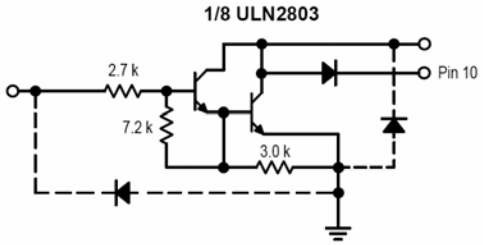
Input Characteristics

ULN2803 Input Current versus Input Voltage



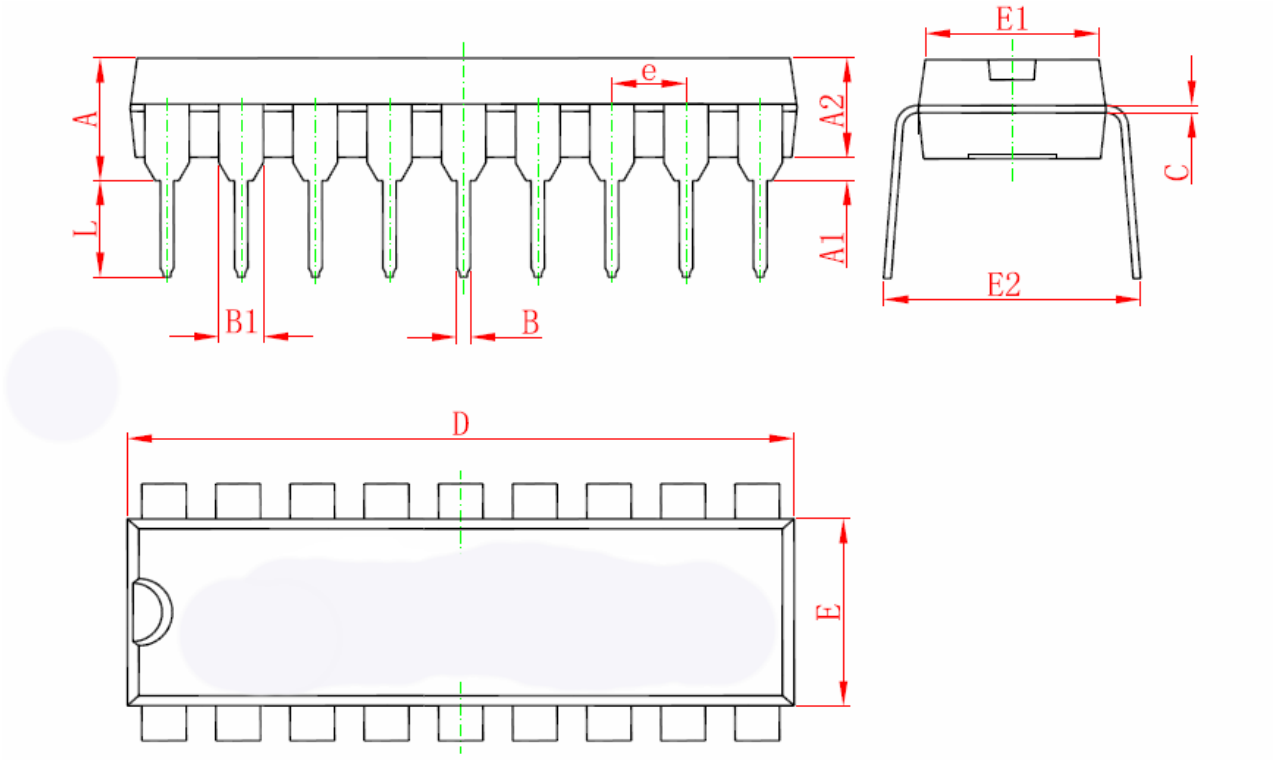
Representative Schematic Diagrams

1/8 ULN2803



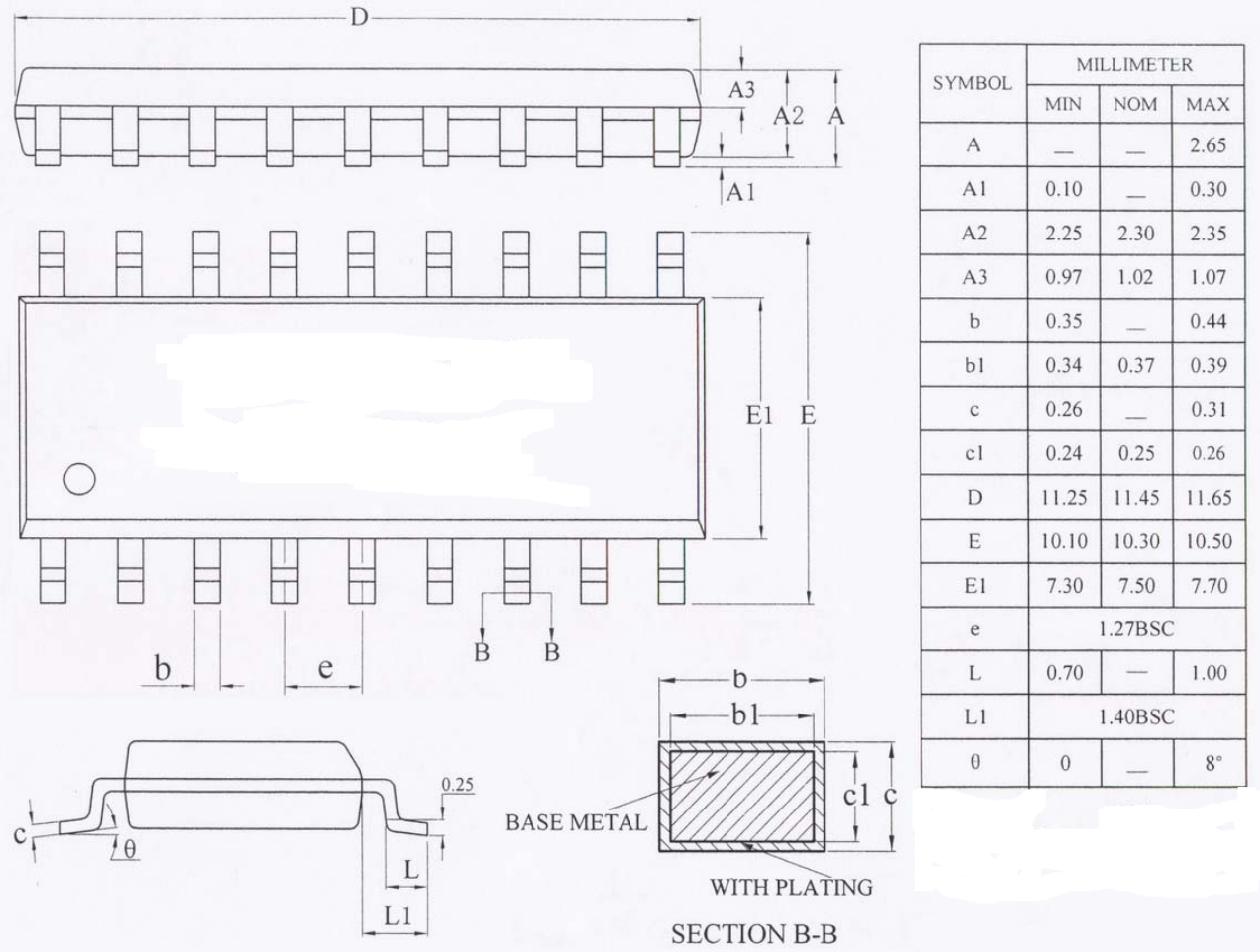
OUTLINE DRAWING

DIP- 18 Unit: mm



Symbol	Dimensions In Millimeters	
	Min	Max
A	3.710	4.310
A1	0.510	
A2	3.200	3.600
B	0.380	0.570
B1	1.524 (BSC)	
C	0.204	0.360
D	22.640	23.040
E	6.200	6.600
E1	7.320	7.920
e	2.540 (BSC)	
L	3.000	3.600
E2	8.400	9.000

SOP-18 Unit:mm



SYMBOL	MILLIMETER		
	MIN	NOM	MAX
A	—	—	2.65
A1	0.10	—	0.30
A2	2.25	2.30	2.35
A3	0.97	1.02	1.07
b	0.35	—	0.44
b1	0.34	0.37	0.39
c	0.26	—	0.31
c1	0.24	0.25	0.26
D	11.25	11.45	11.65
E	10.10	10.30	10.50
E1	7.30	7.50	7.70
e	1.27BSC		
L	0.70	—	1.00
L1	1.40BSC		
θ	0	—	8°

X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Darlington Transistors ***category:***

Click to view products by SLKORMICRO ***manufacturer:***

Other Similar products are found below :

281287X SMMBT6427LT1G 2N7371 BDV64B JANTXV2N6287 028710A SMMBTA64LT1G 2N6350 2SB1214-TL-E SMMBTA14LT1G SBSP52T1G NJVMJD117T4G Jantx2N6058 2N6353 LB1205-L-E 500-00005 2N6053 NJVMJD112G Jan2N6350 Jantx2N6352 Jantx2N6350 BULN2803LVS ULN2001N 2SB1383 2SB1560 2SB852KT146B TIP112TU TIP122TU BCV27 MMBTA13-TP MMBTA14-TP MMSTA28T146 BSP50H6327XTSA1 KSH122TF NTE2557 NJVNJD35N04T4G TIP115 MPSA29-D26Z MJD127T4 FJB102TM BCV26E6327HTSA1 BCV46E6327HTSA1 BCV47E6327HTSA1 BSP61H6327XTSA1 BU941ZPFI 2SB1316TL 2SD1980TL NTE2350 NTE245 NTE246